

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	10/816259	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 09:40
L2	0	"10816259"	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:27
L3	1317	(flash\$3 near5 memory) with ferro\$10	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:29
L4	5103	((flash\$3 \$4volatile) near5 memory) with ferro\$10	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:31
L5	246	polymer near3 ferroelectric with memory	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:31
L6	4	(polymer near3 ferroelectric with memory) with (metal\$5 near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:33
L7	1	"6545384".PN.	USPAT; USOCR	OR	ON	2005/08/22 10:50
L8	1	"6072716".PN.	USPAT; USOCR	OR	ON	2005/08/22 10:50
L9	1	"5705888".PN.	USPAT; USOCR	OR	ON	2005/08/22 10:50
L10	1	"5436742".PN.	USPAT; USOCR	OR	ON	2005/08/22 10:50
L11	284	( ferroelectric with memory) with (metal\$5 near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:51
L12	0	((ferroelectric near5 fluoride) with memory) with (metal\$5 near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:52

L13	0	((ferroelectric with memory) with (metal\$5 near5 intride) near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:53
L14	0	((ferroelectric with memory) with (metal\$5 near5 tride) near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:54
L15	4	((ferroelectric with memory) with (metal\$5 near5 nitride) near5 (electrode plate))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 10:54
L16	3	(polymer near3 ferroelectric with memory) with (metal\$5 near5 nitride)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:37
L17	0	(polymer near3 ferroelectric with memory) with (tatalum near5 nitride)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:40
L18	0	(polymer near3 ferromagnetic with memory) with (tatalum near5 nitride)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:37
L19	0	(polymer near3 ferromagnetic with memory) with (metal near5 nitride)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:39
L20	19	(polymer with memory) with (metal near5 nitride)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 13:39
L21	5	(polymer near3 ferroelectric with memory) with (capacitor)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:05
L22	3	(polymer near3 ferroelectric with memory) with (nitride near5 metal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:06
L23	3	(polymer near4 ferroelectric with memory) with (nitride near5 metal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:06

L24	3	(polymer near5 ferroelectric with memory) with (nitride near5 metal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:06
L25	3	(polymer with ferroelectric with memory) with (nitride near5 metal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:09
L26	19	(polymer with memory) with (nitride near5 metal)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/08/22 14:09